



Original Article

Elastic Deformation and Elastic Wave Velocity for Cubic Metal and Binary Interstitial Alloy's Thin Films at Different Temperatures, Pressures, Interstitial Atomic Concentrations and Film Thicknesses

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Abstract: The theory of elastic deformation and elastic wave for cubic metal and binary interstitial alloy's thin films is built by a statistical moment method (SMM). The obtained results have been applied to perform numerical calculations for W, Au, WSi and AuSi materials. Some SMM calculations for W, Au are compared with experiments and other calculation methods. Other SMM calculations are new and predict experimental results.

Keywords: Binary interstitial alloy, thin film, elastic deformation, elastic wave velocity, SMM

1. Introduction

Statistical moment method (SMM) has been applied to study the elastic deformation and elastic wave velocity of bulk metals, interstitial alloys [1-7] and the thermodynamic properties of metal films [8-10].

Researchers are often interested in stand-mounted films. The average values of the Young's moduli are calculated for Ag, Cu, Al and Ag/Cu multilayers [11]. The biaxial elastic modulus of the α phase agreed with results of bulk α tantalum [12]. Young modulus of nanostructured metallic films is

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measured by experiments [13]. The tensile tests were applied for the freestanding foils and wires [14]. Cu, Ni and Pd layers were deposited on Si wafer substrates by DC-magnetron sputtering. The mechanical stresses were studied by X-ray diffraction measurements [15]. A novel theory predicted the growth mode of a metallic film on an insulating substrate [16]. Studies on mechanical properties of thin films, especially free metal films, are quite limited.

Recently, many mechanical properties of metals and alloy's films have attracted the attention of researchers [8-10, 17-18]. W and WSi are materials having very high melting points [19, 20]. Au and AuSi have many applications [21]. AuSi has long attracted the interest of researchers due to its applications and unusual physical properties. The Young's modulus of Au-3%Si alloy was considered in [22]. Au is often used to make jewelry. According to research [23], AuSi alloy has a color similar to Au and Au alloys can be produced with Si concentrations of 2.5, 2.8 and 3.0%. The hardness of AuSi is about 110 HV and is greater than that of traditional high-purity gold alloys. The temperature dependence of the Young's modulus for Au at zero pressure and in the temperature range from 0 to 1100K has been determined by calculations [24-26] and measured by experiments [27]. The dependence of the volume ratio (V is the volume at pressure P and V_0 is the volume at zero pressure) on pressure for Au at room temperature and in the pressure range from 0 to 1,000 GPa is shown in [24, 28-30]. The pressure dependence of the elastic constant C_{44} in the pressure range from 0 to 100 GPa for Au at room temperature is determined by experiments [31-34]. In this work, we introduce the theory of elastic deformation and elastic wave velocity for cubic binary interstitial alloy's film based on SMM [1-6, 8-10, 17, 21, 35]. The numerical calculations are carried out for films of W, Au, WSi and AuSi.

2. Analytic Calculations

Assume a free thin film of a cubic interstitial alloy AB consisting n^* layers (two outer layers, two next outer layers and $n^* - 4$ inner layers) with thickness d . The number of atoms of these layers respectively are of N^{ol} , N^{nol} and N^{il} [8-10].

A is the atom in pure metal A, A_1 is the main metal atom A at body center (or face center), A_2 is the main metal atom A at vertices and B is the interstitial atom at face center (or body center) of cubic unit cell. For the layer l (the inner layer or the next outer layer), the displacement of the atom X ($X = A, A_1, A_2, B$) at pressure P and temperature T from the equilibrium position has the form [6, 8, 35]

$$y_X^l = \sqrt{\frac{2\gamma_X^l \theta^2}{3(k_X^l)^3}} A_X^l, \quad A_X^l \equiv a_{1X}^l + \sum_{i=2}^6 \left(\frac{\gamma_X^l \theta}{(k_X^l)^2} \right)^i a_{iX}^l, \quad (1)$$

where $\theta = k_{Bo} T$, k_{Bo} is the Boltzmann constant, T is the absolute temperature, $y_X^l \equiv y_X^l(P, T)$, k_X^l and γ_X^l are the harmonic and anharmonic crystal parameters of the atom X in the layer l and are determined from the nearest neighbor distance $r_{1X}^l(P, 0)$ between two atoms at pressure P and temperature $T = 0K$ in the layer l and $r_{1X}^l(P, 0)$ is calculated from the equation of state [35]

$$Pv_X^l = -r_{1X}^l \left(\frac{1}{6} \frac{\partial u_{0X}^l}{\partial r_{1X}^l} + \frac{\hbar \omega_X^l}{4k_X^l} \frac{\partial k_X^l}{\partial r_{1X}^l} \right), \quad (2)$$

u_{0X}^1 is the cohesive energy, $v_X^1 = \frac{4r_{1X}^{13}}{3\sqrt{3}}$ is the volume of cubic unit cell for BCC lattice, $v_X^1 = \frac{r_{1X}^{13}}{\sqrt{2}}$ is the volume of cubic unit cell for FCC lattice, m_X^1 is the mass for the atom X in the layer 1 and a_{1X}^1 are complex functions of $Y_X^1 \equiv x_X^1 \coth x_X^1$.

For the outer layer [6, 8, 35],

$$y_X^{ol} = -\frac{\gamma_X^{ol}\theta}{(k_X^{ol})^2} Y_X^{ol}, \quad Y_X^{ol} \equiv x_X^{ol} \coth x_X^{ol}, \quad (3)$$

where $k_X^{ol}, \gamma_X^{ol}, x_X^{ol}$ are determined in the same way as above.

For the layer m (the inner layer, the next outer layer or the outer layer) [6, 8, 35],

$$\begin{aligned} r_{1B}^m(P, T) &= r_{1B}^m(P, 0) + y_{A_1}^m(P, T), r_{1A}^m(P, T) = r_{1A}^m(P, 0) + y_A^m(P, T), \\ r_{1A_1}^m(P, T) &= r_{1B}^m(P, T), r_{1A_2}^m(P, T) = r_{1A_2}^m(P, 0) + y_B^m(P, T). \end{aligned} \quad (4)$$

The mean nearest neighbor distance $\overline{r_{1A}^m(P, T)}$ between two atoms A in the layer m is determined by [6]

$$\begin{aligned} \overline{r_{1A}^m(P, T)} &= \overline{r_{1A}^m(P, 0)} + \overline{y^m(P, T)}, \overline{r_{1A}^m(P, 0)} = (1 - c_B^m) r_{1A}^m(P, 0) + c_B^m r_{1A}^m(P, 0), \\ \overline{y^m(P, T)} &= \sum_X c_X^m y_X^m(P, T), \end{aligned} \quad (5)$$

where $r_{1A}^m(P, 0) = \sqrt{3} r_{1B}^m(P, 0)$, $c_A^m = 1 - 7c_B^m, c_{A_1}^m = 2c_B^m, c_{A_2}^m = 4c_B^m$ for BCC lattice $r_{1A}^m(P, 0) = \sqrt{2} r_{1B}^m(P, 0)$, $c_A^m = 1 - 15c_B^m, c_{A_1}^m = 6c_B^m, c_{A_2}^m = 8c_B^m$ for FCC lattice, $c_X^m = \frac{N_X^m}{N^m}$ is the concentration of atoms X in the layer m , N_X^m is the the number of atoms X in the layer m and N^m is the number of atoms in the layer m .

The Helmholtz free energy for the layer 1 of alloy film has the form [6, 35]

$$\begin{aligned} \Psi^1 &= N^1 \left(\sum_X c_X^1 \psi_X^1 - TS_c^1 \right), \\ \Psi_X^1 &= N^1 \psi_X^1 \approx U_{0X}^1 + 3N^1 \theta [x_X^1 + \ln(1 - e^{-2x_X^1})] + \\ &\quad + \frac{3N^1 \theta^2}{(k_X^1)^2} \left[\gamma_{2X}^1 (Y_X^1)^2 - \frac{2\gamma_{1X}^1}{3} \left(1 + \frac{Y_X^1}{2} \right) \right] + \\ &\quad + \frac{6N^1 \theta^3}{(k_X^1)^4} \left[\frac{4}{3} (\gamma_{2X}^1)^2 \left(1 + \frac{Y_X^1}{2} \right) Y_X^1 - 2 \left((\gamma_{1X}^1)^2 + 2\gamma_{1X}^1 \gamma_{2X}^1 \right) \left(1 + \frac{Y_X^1}{2} \right) (1 + Y_X^1) \right]. \end{aligned} \quad (6)$$

The Helmholtz free energy of the outer layer has the form [6, 35]

$$\Psi^{ol} = N^{ol} \left(\sum_X c_X^{ol} \psi_X^{ol} - TS_c^{ol} \right),$$

$$\Psi_X^{ol} = N^{ol} \psi_X^{ol} \approx U_0^{ol} + 3N^{ol} \theta [x_X^{ol} + \ln(1 - e^{-2x_X^{ol}})]. \quad (7)$$

In Eqs. (6) and (7), $U_{0X}^m = \frac{N^m}{2} u_{0X}^m$, ψ_X^m is the Helmholtz free energy of an atom X in the layer m and S_c^m is the configurational entropy of the alloy in the layer m .

The Helmholtz free energies of the layer m in the harmonic approximation have the form [6, 8, 35]

$$\Psi^m = N^m \left(\sum_X c_X^m \psi_X^m - TS_c^m \right),$$

$$\Psi_X^m = N^m \psi_X^m \approx U_0^m + 3N^m \theta [x_X^m + \ln(1 - e^{-2x_X^m})]. \quad (8)$$

The Helmholtz free energies for an atom of the BCC and FCC films respectively have the form [8]

$$\begin{aligned} \frac{\Psi}{N} &= \frac{d\sqrt{3}-3\bar{a}}{d\sqrt{3}+\bar{a}} \psi^{tr} + \frac{2\bar{a}}{d\sqrt{3}+\bar{a}} \psi^{ng} + \frac{2\bar{a}}{d\sqrt{3}+\bar{a}} \psi^{ng1} - \frac{TS_c}{N} = \\ &= \frac{d\sqrt{3}-3\bar{a}}{d\sqrt{3}+\bar{a}} \left(\sum_X c_X^{tr} \psi_X^{tr} - TS_c^{tr} \right) + \frac{2\bar{a}}{d\sqrt{3}+\bar{a}} \left(\sum_X c_X^{ng} \psi_X^{ng} - TS_c^{ng} \right) + \\ &\quad + \frac{2\bar{a}}{d\sqrt{3}+\bar{a}} \left(\sum_X c_X^{ng1} \psi_X^{ng1} - TS_c^{ng1} \right) - \frac{TS_c}{N}, \end{aligned} \quad (9)$$

$$\begin{aligned} \frac{\Psi}{N} &= \frac{d\sqrt{2}-3\bar{a}}{d\sqrt{2}+\bar{a}} \psi^{il} + \frac{2\bar{a}}{d\sqrt{2}+\bar{a}} \psi^{ol} + \frac{2\bar{a}}{d\sqrt{2}+\bar{a}} \psi^{nol} - \frac{TS_c}{N} = \\ &= \frac{d\sqrt{2}-3\bar{a}}{d\sqrt{2}+\bar{a}} \left(\sum_X c_X^{il} \psi_X^{il} - TS_c^{il} \right) + \frac{2\bar{a}}{d\sqrt{2}+\bar{a}} \left(\sum_X c_X^{ol} \psi_X^{ol} - TS_c^{ol} \right) + \\ &\quad + \frac{2\bar{a}}{d\sqrt{2}+\bar{a}} \left(\sum_X c_X^{nol} \psi_X^{nol} - TS_c^{nol} \right) - \frac{TS_c}{N}, \end{aligned} \quad (10)$$

where $N = N^{il} + N^{nol} + N^{ol}$, S_c is the configurational entropy of the film, $\psi^{il}, \psi^{nol}, \psi^{ol}$ respectively are the Helmholtz free energies of an atom in the inner layer, the next outer layer and the outer layer of the film, \bar{a} is the mean nearest neighbor distance between two atoms, \bar{b} is the average thickness of the two respective layers and \bar{a}_c is the average lattice constant of the film

For body-centered cube (BCC) film [8],

$$\bar{b} = \frac{\bar{a}}{\sqrt{3}}, \quad \bar{a}_c = 2\bar{b} = \frac{2\bar{a}}{\sqrt{3}}, \quad n^* = 1 + \frac{d\sqrt{3}}{\bar{a}}. \quad (11)$$

For face-centered cube (FCC) film [8],

$$\bar{b} = \frac{\bar{a}}{\sqrt{2}}, \quad \bar{a}_c = 2\bar{b} = \sqrt{2}\bar{a}, \quad n^* = 1 + \frac{d\sqrt{2}}{\bar{a}}. \quad (12)$$

The Young moduli of the BCC and FCC films have the form [1, 6]

$$E_{YAB} = \frac{d\sqrt{3}-3\bar{a}}{d\sqrt{3}+\bar{a}} E_Y^{il} + \frac{2\bar{a}}{d\sqrt{3}+\bar{a}} E_Y^{ol} + \frac{2\bar{a}}{d\sqrt{3}+\bar{a}} E_Y^{nol}, \quad (13)$$

$$E_{YAB} = \frac{d\sqrt{2}-3\bar{a}}{d\sqrt{2}+\bar{a}} E_Y^{il} + \frac{2\bar{a}}{d\sqrt{2}+\bar{a}} E_Y^{ol} + \frac{2\bar{a}}{d\sqrt{2}+\bar{a}} E_Y^{nol}, \quad (14)$$

where

$$E_Y^m = \sum_X c_X E_{YX}^m, E_{YX}^m = \frac{1}{\pi(r_{01X}^m + y_X^m) A_{1X}^m}, A_{1X}^m = \frac{1}{k_X^m} \left[1 + \frac{2(\gamma_X^m)^2 \theta^2}{(k_X^m)^4} \left(1 + \frac{Y_X^m}{2} \right) (1 + Y_X^m) \right]. \quad (15)$$

The bulk modulus, the shearing modulus, the elastic constants, the longitudinal wave velocity and the transverse wave velocity of the film respectively are given by [1, 6]

$$K_{AB} = \frac{E_{YAB}}{3(1-2\nu_{AB})}, G_{AB} = \frac{E_{YAB}}{2(1+\nu_{AB})}, \quad (16)$$

$$C_{11AB} = \frac{E_{YAB}(1-\nu_{AB})}{(1+\nu_{AB})(1-2\nu_{AB})}, C_{12AB} = \frac{E_{YAB}\nu_{AB}}{(1+\nu_{AB})(1-2\nu_{AB})}, C_{44AB} = \frac{E_{YAB}}{2(1+\nu_{AB})}, \quad (17)$$

$$V_{ABd} = \sqrt{\frac{2C_{44AB} + C_{12AB}}{\rho_{AB}}}, V_{ABn} = \sqrt{\frac{C_{44AB}}{\rho_{AB}}}, \quad (18)$$

where

$$\nu_{AB} = c_A \nu_A + c_B \nu_B \approx \nu_A, \quad (20)$$

ν_{AB} is the Poisson ratio of the alloy film AB, ν_A , ν_B are the Poisson ratios of materials A and B.

Because $c_B \ll c_A$ then $\nu_{AB} \approx \nu_A$. $\rho_{AB} = \frac{m_{AB}}{V_{AB}} \approx \rho_A$, $V_{AB} = N\nu_{AB}$, ρ_{AB} is the density of the alloy

film AB, ρ_A is the density of the main metal A and V_{AB} is the volume of the alloy film AB.

The cohesive energy u_0 and crystal parameters $k, \gamma_1, \gamma_2, \gamma$ for the atom B in the approximation of two coordination spheres, the atoms A_1 and A_2 in the approximation of three coordination spheres for the inner layer of the film have the form as in bulk material for BCC lattice [6, 8, 35] and for FCC lattice [36].

The cohesive energy u_0 and crystal parameters $k, \gamma_1, \gamma_2, \gamma$ for the atom B in the approximation of two coordination spheres, the atoms A_1 and A_2 in the approximation of three coordination spheres for the next outer layer (there is a vacancy on the z-axis in the second coordination sphere taking $u_0, k, \gamma_1, \gamma_2, \gamma$ of the atom B and in the third coordination sphere taking $u_0, \gamma_1, \gamma_2, \gamma$ of the atoms A_1 and A_2) of the film for FCC lattice have the form as in [36] and for BCC lattice have the form as in [6, 8, 35].

The cohesive energy u_0 and crystal parameters $k, \gamma_1, \gamma_2, \gamma$ for the atom B in the approximation of two coordination spheres, the atoms A_1 and A_2 in the approximation of three coordination spheres for the outer layer (remove an atom on the second coordination sphere taking $u_0, k, \gamma_1, \gamma_2, \gamma$ of the atom

B and on the third coordination sphere taking taking $u_0, \gamma_1, \gamma_2, \gamma$ of the atoms A_1 and A_2 of the film for FCC lattice have the form as in [7] and for BCC lattice have the form as in [6, 8, 35].

When thickness d of the thin film is large enough, the theory of elastic deformation and elastic wave velocity for the cubic interstitial alloy AB's film becomes that for the cubic interstitial alloy AB. When the interstitial atom concentration is zero, the theory of elastic deformation and elastic wave velocity for the cubic interstitial alloy AB's film becomes that for the cubic main metal A's film.

We perform numerical calculations according to above mentioned theory for W, Au, WSi and AuSi in section 3.

3. Numerial Calculations and Discussions for W, Au, WSi and AuSi

For interactions W-W, Au-Au, Si-Si in W, Au, WSi and AuSi, we use the Mie-Lennard-Jones potential [37]

$$\varphi(r) = \frac{D}{n-m} \left[m \left(\frac{r_0}{r} \right)^n - n \left(\frac{r_0}{r} \right)^m \right], \quad (21)$$

where the potential parameters D, r_0, m, n are given in Table 1. We use the following approximations

$$\varphi_{W-Si} \approx \frac{1}{2} (\varphi_{W-W} + \varphi_{Si-Si}), \varphi_{Au-Si} \approx \frac{1}{2} (\varphi_{Au-Au} + \varphi_{Si-Si}). \quad (22)$$

Table 1. The parameters D, r_0, m, n of the Mie-Lennard-Jones potential [23]

Interaction	m	n	$D(10^{-16}\text{erg})$	$r_0(10^{-10}\text{m})$
W-W [37]	6.5	10.5	15564.744	2.7365
Au-Au [37]	5.5	10.5	4683	2.8751
Si-Si [37]	6.0	12.0	45128.24	2.295

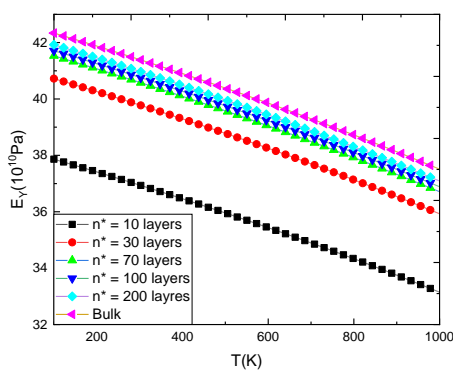


Figure 1. $E_Y(T, n^*)$ for W at $P = 0$ calculated by SMM.

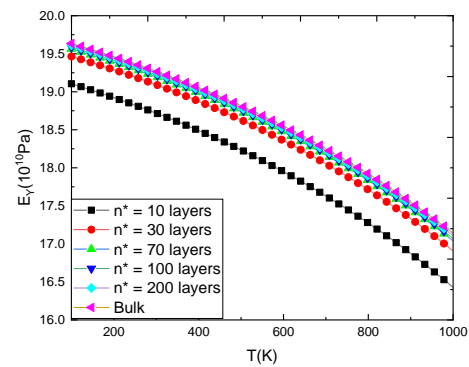


Figure 2. $E_Y(T, n^*)$ for WSi at $c_{Si} = 5\%$, $P = 0$ calculated by SMM.

The temperature and layer number dependences of Young modulus for W and Au at $P = 0$ calculated by SMM are shown in Figs. 1 and 5. The temperature and layer number dependences of Young modulus for WSi and AuSi at $c_{\text{Si}} = 5\%$, $P = 0$ calculated by SMM are shown in Figs. 2 and 6. The pressure and layer number dependences of Young modulus for W and Au at $T = 300\text{K}$ calculated by SMM are shown in Figs. 3 and 7. The pressure and layer number dependences of Young modulus for WSi and AuSi at $c_{\text{Si}} = 5\%$, $T = 300\text{K}$ calculated by SMM are shown in Figs. 4 and 8.

The nearest neighbor distance of a film strongly depends on thickness, temperature and pressure. This distance increases with the increase of thickness, increases sharply with the increase of temperature and decreases with the increase of pressure. As the number of layers increases until about 200 layers (about 35 nm thickness), elastic deformation and elastic wave velocity quantities of the film approach the values of bulk material.

Silicon concentration and layer number dependences of nearest neighbor distance and mean nearest neighbor a , elastic moduli E_Y , K , G , elastic constants C_{11} , C_{12} , C_{44} , longitudinal velocity V_l and transverse V_t for films W, Au, WSi and AuSi at $P = 0$, $T = 300\text{K}$ calculated by SMM are summarised in Tables 2 and 3. Pressure and layer number dependences of longitudinal velocity and transverse velocity for Au at $T = 300\text{K}$ calculated by SMM are summarised in Table 4.

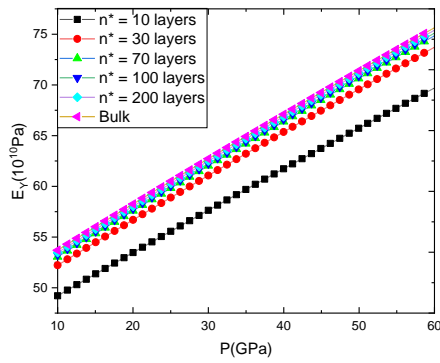


Figure 3. $E_Y(P, n^*)$ for W at $T = 300\text{K}$ calculated by SMM.

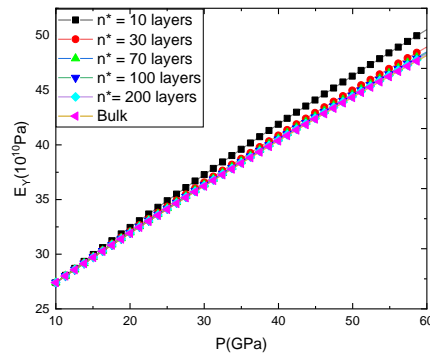


Figure 4. $E_Y(P, n^*)$ for WSi at $c_{\text{Si}} = 5\%$, $T = 300\text{K}$ calculated by SMM.

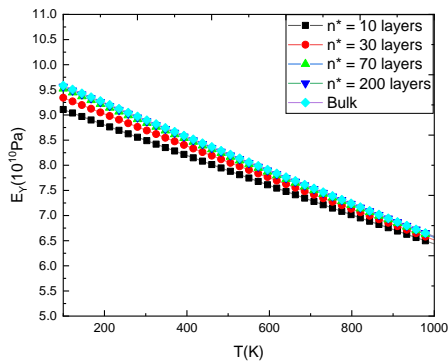


Figure 5. $E_Y(T, n^*)$ for Au at $P = 0$ calculated by SMM.

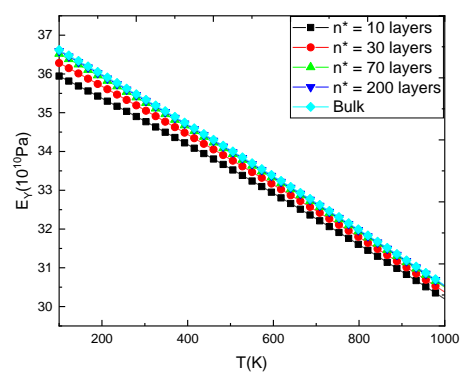


Figure 6. $E_Y(T, n^*)$ for AuSi at $c_{\text{Si}} = 5\%$, $P = 0$ calculated by SMM.

Table 2. $a(c_{\text{Si}}, n^*)$, $E_Y(c_{\text{Si}}, n^*)$, $K(c_{\text{Si}}, n^*)$, $G(c_{\text{Si}}, n^*)$, $C_{11}(c_{\text{Si}}, n^*)$, $C_{12}(c_{\text{Si}}, n^*)$, $C_{44}(c_{\text{Si}}, n^*)$, $V_t(c_{\text{Si}}, n^*)$ and $V_l(c_{\text{Si}}, n^*)$ for films W and WSi at $P = 0$, $T = 300\text{K}$ calculated by SMM

Layer number	$c_{\text{Si}}(\%)$	0	1	3	5
	$a(10^{-10}\text{m})$	2.642	2.658	2.690	2.722
	$E_Y(10^{10}\text{Pa})$	38.76	33.91	25.81	19.47
	$G(10^{10}\text{Pa})$	29.36	25.88	19.99	15.31
10	$K(10^{10}\text{Pa})$	15.14	13.23	10.05	7.56
	$C_{11}(10^{10}\text{Pa})$	4.96	4.35	3.34	2.54
	$C_{12}(10^{10}\text{Pa})$	1.93	1.71	1.33	1.03
	$C_{44}(10^{10}\text{Pa})$	1.51	1.32	1.00	0.76
	$V_t(10^5\text{cm/s})$	4.69	4.39	3.85	3.35
	$V_l(10^5\text{cm/s})$	2.59	2.42	2.11	1.83
	$a(10^{-10}\text{m})$	2.649	2.665	2.697	2.730
	$E_Y(10^{10}\text{Pa})$	40.85	35.34	26.28	19.32
	$G(10^{10}\text{Pa})$	30.95	26.97	20.35	15.18
70	$K(10^{10}\text{Pa})$	15.96	13.79	10.23	7.50
	$C_{11}(10^{10}\text{Pa})$	5.22	4.54	3.40	2.52
	$C_{12}(10^{10}\text{Pa})$	2.03	1.78	1.35	1.02
	$C_{44}(10^{10}\text{Pa})$	1.60	1.38	1.02	0.75
	$V_t(10^5\text{cm/s})$	4.81	4.48	3.88	3.34
	$V_l(10^5\text{cm/s})$	2.66	2.47	2.13	1.82
	$a(10^{-10}\text{m})$	2.649	2.666	2.698	2.731
	$E_Y(10^{10}\text{Pa})$	41.07	35.50	26.32	19.30
	$G(10^{10}\text{Pa})$	31.11	27.09	20.39	15.17
200	$K(10^{10}\text{Pa})$	16.04	13.85	10.24	7.49
	$C_{11}(10^{10}\text{Pa})$	5.25	4.56	3.40	2.52
	$C_{12}(10^{10}\text{Pa})$	2.04	1.79	1.36	1.02
	$C_{44}(10^{10}\text{Pa})$	1.60	1.38	1.02	0.75
	$V_t(10^5\text{cm/s})$	4.82	4.49	3.88	3.34
	$V_l(10^5\text{cm/s})$	2.67	2.48	2.13	1.82
	$a(10^{-10}\text{m})$	2.649	2.666	2.698	2.731
	$E_Y(10^{10}\text{Pa})$	41.19	35.57	26.35	19.29
	$G(10^{10}\text{Pa})$	31.20	27.15	20.67	15.22
Bulk	$K(10^{10}\text{Pa})$	16.09	13.88	10.23	7.483
	$C_{11}(10^{10}\text{Pa})$	5.26	4.56	3.43	2.52
	$C_{12}(10^{10}\text{Pa})$	2.05	1.78	1.38	1.02
	$C_{44}(10^{10}\text{Pa})$	1.61	1.39	1.02	0.74
	$V_t(10^5\text{cm/s})$	4.83	4.49	3.89	3.34
	$V_l(10^5\text{cm/s})$	2.67	2.47	2.13	1.82

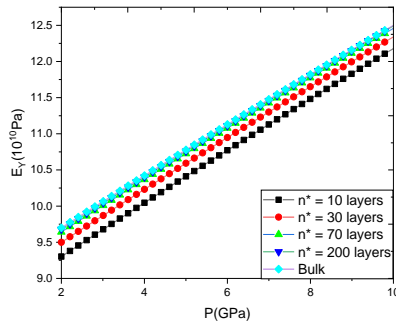


Figure 7. $E_Y(P, n^*)$ for Au at $T = 300\text{K}$ calculated by SMM.

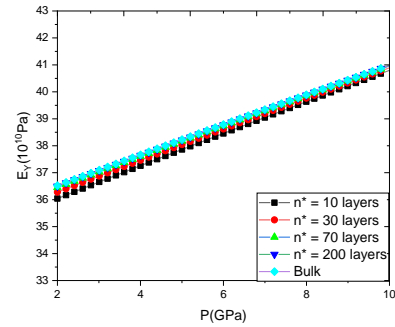


Figure 8. $E_Y(P, n^*)$ for AuSi at $c_{\text{Si}} = 5\%$, $T = 300\text{K}$ calculated by SMM.

Table 3. $a(c_{\text{Si}}, n^*)$, $E_Y(c_{\text{Si}}, n^*)$, $K(c_{\text{Si}}, n^*)$, $G(c_{\text{Si}}, n^*)$, $C_{11}(c_{\text{Si}}, n^*)$, $C_{12}(c_{\text{Si}}, n^*)$, $C_{44}(c_{\text{Si}}, n^*)$, $V_t(c_{\text{Si}}, n^*)$ and $V_l(c_{\text{Si}}, n^*)$ for films Au and AuSi at $P = 0$, $T = 300\text{K}$ calculated by SMM

Layer number	$c_{\text{Si}}(\%)$	0	1	3	5
10	$a(10^{-10}\text{m})$	2.84	2.85	2.86	2.87
	$E_Y(10^{10}\text{Pa})$	8.54	13.79	24.29	34.79
	$G(10^{10}\text{Pa})$	14.24	22.71	39.08	54.70
	$K(10^{10}\text{Pa})$	3.05	4.93	8.70	12.48
	$C_{11}(10^{10}\text{Pa})$	18.31	29.29	50.68	71.34
	$C_{12}(10^{10}\text{Pa})$	12.20	19.43	33.28	46.38
	$C_{44}(10^{10}\text{Pa})$	3.05	4.93	8.70	12.48
	$V_t (10^5\text{cm/s})$	3.08	3.90	5.12	6.08
70	$V_l (10^5\text{cm/s})$	1.26	1.60	2.12	2.54
	$a(10^{-10}\text{m})$	2.85	2.85	2.86	2.87
	$E_Y(10^{10}\text{Pa})$	8.90	14.17	24.72	35.27
	$G(10^{10}\text{Pa})$	14.83	23.34	39.77	55.46
	$K(10^{10}\text{Pa})$	3.18	5.07	8.85	12.65
	$C_{11}(10^{10}\text{Pa})$	19.07	30.10	51.58	72.33
	$C_{12}(10^{10}\text{Pa})$	12.71	19.96	33.87	4.03
	$C_{44}(10^{10}\text{Pa})$	3.18	5.07	8.85	12.65
200	$V_t (10^5\text{cm/s})$	3.14	3.95	5.17	6.12
	$V_l (10^5\text{cm/s})$	1.28	1.62	2.14	2.56
	$a(10^{-10}\text{m})$	2.85	2.85	2.86	2.87
	$E_Y(10^{10}\text{Pa})$	8.94	1.21	24.77	35.33
	$G(10^{10}\text{Pa})$	14.89	23.41	39.85	55.54
	$K(10^{10}\text{Pa})$	3.19	5.08	8.87	12.67
	$C_{11}(10^{10}\text{Pa})$	19.15	30.18	51.67	72.44
	$C_{12}(10^{10}\text{Pa})$	12.77	20.02	33.94	47.10

	$C_{44}(10^{10}\text{Pa})$	3.19	5.08	8.87	12.67
	$V_t (10^5\text{cm/s})$	3.15	3.95	5.17	6.13
	$V_l (10^5\text{cm/s})$	1.29	1.62	2.14	2.56
	$a(10^{-10}\text{m})$	2.85	2.85	2.86	2.87
	$E_V(10^{10}\text{Pa})$	8.96	14.24	24.80	35.35
	$G(10^{10}\text{Pa})$	14.93	23.45	39.89	55.59
Bulk	$K(10^{10}\text{Pa})$	3.20	5.09	8.88	12.68
	$C_{11}(10^{10}\text{Pa})$	19.19	30.23	51.73	72.49
	$C_{12}(10^{10}\text{Pa})$	12.80	20.05	33.97	47.13
	$C_{44}(10^{10}\text{Pa})$	3.20	5.09	8.88	12.68
	$V_t (10^5\text{cm/s})$	3.15	3.96	5.18	6.13
	$V_l (10^5\text{cm/s})$	1.29	1.62	2.14	2.56

Table 4. $V_l(P, n^*)$ and $V_t(P, n^*)$ for Au at $T = 300\text{K}$ calculated by SMM

	Layer number	10 GPa	20 GPa	30 GPa	40 GPa	50 GPa
V_l (10^5cm/s)	10	3.21	3.34	3.46	3.57	3.68
	30	3.25	3.37	3.49	3.60	3.70
	70	3.27	3.39	3.51	3.61	3.72
	200	3.28	3.40	3.51	3.62	3.72
	Bulk	1.31	1.36	1.41	1.46	1.50
V_t (10^5cm/s)	10	1.33	1.38	1.42	1.47	1.51
	30	1.34	1.38	1.43	1.48	1.52
	70	1.38	1.39	1.43	1.48	1.52
	200	3.21	3.34	3.46	3.57	3.68
	Bulk	3.25	3.37	3.49	3.60	3.70

The value of isothermal bulk modulus B_T of W in bulk material form at $T = 300\text{K}$, $P = 0$ calculated by SMM is in good agreement with experiment results shown in [8-10] and better than other calculations in [16] (see Table 5).

Table 5. K of bulk W at $T = 300\text{K}$, $P = 0$ calculated by SMM, LDA [5], TB [5] and from EXPT [11, 16, 19]

Method	SMM	EXPT [8-10]	LDA [16]	TB [16]
$K(10^{10}\text{Pa})$	314	323	333	319

(LDA is the calculated result in the approximation of local density and TB is the calculation by tight-binding method).

The values of nearest neighbor distance a and elastic moduli E_V , G , K of W in bulk material form at $T = 300\text{K}$, $P = 0$ calculated by SMM are in good agreement with experiment results in [21, 35, 38, 39] (see Table 6).

Table 6. a , E_Y , G , K of bulk W at $T = 300\text{K}$, $P = 0$ calculated by SMM and from EXPT [4, 38, 40]

Method	$a(10^{-10}\text{m})$ EXPT [38, 40]	$E_Y(10^{10}\text{Pa})$ EXPT [38]	$K(10^{10}\text{Pa})$ EXPT [41]	$G(10^{10}\text{Pa})$ EXPT [38]
SMM	2.6443	41.40	31.36	16.17
TN[38,40, 41]	2.7400	41.50	30.00	16.00

The values of elastic constants C_{11} , C_{12} , C_{44} of W in bulk material form at $T = 300\text{K}$, $P = 0$ calculated by SMM are in good agreement with experiment results shown in [6, 13, 39] (see Table 7)

Table 7. C_{11} , C_{12} , C_{44} of bulk W at $T = 300\text{K}$, $P = 0$ calculated by SMM and from EXPT [38, 40, 42]

Method	SMM	EXPT [38]	EXPT [40]	EXPT [42]
$C_{11}(10^{11}\text{Pa})$	5.29	5.27	5.21	5.29
$C_{12}(10^{11}\text{Pa})$	2.06	1.94	2.02	1.70
$C_{44}(10^{11}\text{Pa})$	1.62	1.47	1.60	1.98

For bulk Au at near melting temperature, the atomic volume $V = 17.29 \times 10^{-30} \text{ m}^3$ calculated by SMM and $V = 17.88 \times 10^{-30} \text{ m}^3$ according other calculations [41]. Clearly, these calculations are consistent. The values of nearest neighbor distance a and elastic moduli E_Y , G , K of Au in bulk material form at $T = 300\text{K}$, $P = 0$ calculated by SMM are in good agreement with experiment results shown in [35, 39, 43] (see Table 8).

Table 8. a , E_Y , G , K of bulk Au at $T = 300\text{K}$, $P = 0$ calculated by SMM and from EXPT [35, 39, 43]

Method	$a(10^{-10}\text{m})$ EXPT [39, 43]	$E(10^{10}\text{Pa})$ EXPT [35]	$K(10^{10}\text{Pa})$ EXPT [35]	$G(10^{10}\text{Pa})$ EXPT [35]
SMM	2.8454	8.96	14.94	3.20
EXPT [35,39,43]	2.8838	8.91	16.70	3.10

The values of elastic constants C_{11} , C_{12} , C_{44} of Au in bulk material form at $T = 300\text{K}$, $P = 0$ calculated by SMM are in good agreement with experiment results shown in [38, 39] (see Table 9).

Table 9. C_{11} , C_{12} , C_{44} of bulk W at $T = 300\text{K}$, $P = 0$ calculated by SMM and from EXPT [38, 39]

Method	SMM	EXPT [38, 39]
$C_{11}(10^{11}\text{Pa})$	1.92	1.92
$C_{12}(10^{11}\text{Pa})$	1.28	1.63
$C_{44}(10^{11}\text{Pa})$	0.32	0.42

We found no theoretical or experimental evidence for the dependence of Young's modulus on interstitial atom concentration for WSi and AuSi. However, for alloys close to AuSi and CuSi, the experiments in [44-46] have shown a decrease in Young's modulus and elastic constant C_{44} with increasing Si atomic concentration.

4. Conclusion

On the basis of the model and the theory of elastic deformation and elastic wave velocity for cubic metals and cubic binary interstitial alloy's thin films builded by the SMM, we performed numerical

calculations for films W, Au, WSi and AuSi from 100 to 1,000K, from zero to 10 GPa, from zero to 5% of interstitial atom concentration and from 10 to 200 layers. At zero interstitial atom concentration, the elastic deformation and elastic wave velocity of alloy film becomes that of main metal film. The Young modulus of alloy film decreases with the increase of temperature and increases with the increase of pressure. The Young modulus of alloy film decreases with interstitial atom concentration for film WSi and increases with interstitial atom concentration for film AuSi. As the number of layers increases until about 200 layers (at 35 nm thickness for Au and AuSi and at 30 nm for W and WSi), the elastic deformation and elastic wave velocity of alloy film approaches the values of bulk material. SMM calculations for nearest neighbor distance and elastic deformation and elastic wave velocity for bulk Au are in good agreement with the results obtained by experiments and other calculations. Numerical results without comparative data are new results and are a reference source for prediction and experimental orientation in the future.

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